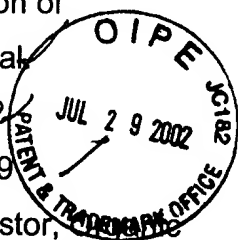


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)
Yukio YAMAUCHI et al)
Serial No. 09/266,012)
Filed: March 11, 1999)
For: Thin Film Transistor,)
Electroluminescence Display Device)
And Manufacturing Method Of The)
Same)

Art Unit: 2822

Examiner: N. D. Richards



RECEIVED

AUG 6 2002

TECHNOLOGY CENTER 2800

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with
The United States Postal Service with sufficient postage as First
Class Mail in an envelope addressed to: Commissioner for Patents,
Washington, D.C. 20231, on 7/22/02

#23/E

J. McQuillan
8/8/02

AMENDMENT AND REQUEST FOR INTERFERENCE UNDER 37 CFR 1.607

Honorable Commissioner of Patents

Washington, D.C. 20231

Sir:

In response to the Office Action dated March 20, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

1. An electroluminescence display device comprising:
- a substrate having an insulating surface;
 - a thin film transistor formed over said substrate, said thin film transistor comprising an active layer comprising crystalline silicon including source, drain and channel regions;
 - an electrode comprising aluminum electrically connected to one of said source and drain regions;
 - a barrier metal layer interposed between said electrode and said one of the source and drain regions to prevent a direct contact therebetween;
 - a transparent electrode electrically connected to said thin film transistor; and
 - an electroluminescence layer comprising an organic material adjacent to said transparent electrode,
- wherein said barrier metal layer comprises titanium.